## MARKING SCHEME

SET 55/1/1 (Compartment)

| Q. No. | Expected Answer / Value Points | Marks | Total Marks |
| :---: | :---: | :---: | :---: |
| Section A |  |  |  |
| $\begin{aligned} & \text { Set1,Q1 } \\ & \text { Set2,Q4 } \\ & \text { Set3,Q3 } \end{aligned}$ | Kinetic energy will not be affected. | 1 | 1 |
| $\begin{aligned} & \text { Set1,Q2 } \\ & \text { Set2,Q5 } \\ & \text { Set3,Q4 } \end{aligned}$ | Clockwise on the side of the observer. <br> [Alternatively :The candidate who draws diagram with arrow indicating the direction correctly, may also be given full credit.] | 1 | 1 |
| $\begin{aligned} & \hline \text { Set1,Q3 } \\ & \text { Set2,Q1 } \\ & \text { Set3,Q5 } \\ & \hline \end{aligned}$ | (i) Real (ii) magnified | $1 / 2+1 / 2$ | 1 |
| $\begin{aligned} & \hline \text { Set1,Q4 } \\ & \text { Set2,Q2 } \\ & \text { Set3,Q1 } \end{aligned}$ |  | 1 | 1 |
| $\begin{aligned} & \hline \text { Set1,Q5 } \\ & \text { Set2,Q3 } \\ & \text { Set3,Q2 } \end{aligned}$ | To avoid overlapping of the two signals | 1 | 1 |
| Section B |  |  |  |
| $\begin{aligned} & \text { Set1,Q6 } \\ & \text { Set2,Q10 } \\ & \text { Set3,Q8 } \end{aligned}$ | Drift velocity $v_{d}=\frac{e E}{m} \tau(\tau=$ relaxation time $)$ <br> The current $I=n e A v_{d}(n=$ number of charge carriers per unit volume.) $\begin{aligned} & j=\frac{n e^{2}}{m} \tau E \\ & j=\frac{1}{\rho} E \end{aligned}$ | $1 / 2$ <br> $1 / 2$ <br> $1 / 2$ <br> $1 / 2$ | 2 |
| $\begin{aligned} & \hline \text { Set1,Q7 } \\ & \text { Set2,Q6 } \\ & \text { Set3,Q9 } \end{aligned}$ | Unpolarised light and linearly polarized light $1 / 2+1 / 2$ <br> Diagram \& description $1 / 2+1 / 2$ <br> For unpolarised light electric vector associated with light, is oscillating randomly in all directions in a plane perpendicular to the direction of propagation of light. <br> In linearly polarised light oscillating electric vector gets aligned along one direction perpendicular to the direction of propagation of light. | $\begin{aligned} & 1 / 2 \\ & 1 / 2 \end{aligned}$ |  |



|  | Explanation of conversion of mass into energy (vice versa) <br> Example |  |  |
| :--- | :--- | :--- | :--- | :--- |
|  | Since proton number and neutron number are conserved, the total rest mass of <br> neutron and protons is the same on either side of the nuclear reaction. But <br> total binding energy of nuclei on the left side need not be the same as that on <br> the right hand side. The difference in binding energy causes a release of <br> energy in the reaction. <br> Example : <br> ${ }_{1}^{2} \mathrm{H}+{ }_{1}^{2} \mathrm{H} \rightarrow{ }_{2}^{3} \mathrm{He}+{ }_{0}^{1} n+$ energy | 1 |  |

\begin{tabular}{|c|c|c|c|}
\hline \& \begin{tabular}{l}
\[
\begin{gathered}
\frac{q_{1}}{4 \pi \varepsilon_{o} R_{1}}=\frac{q_{2}}{4 \pi \varepsilon_{o} R_{1}} \Rightarrow \frac{q_{1}}{R_{1}}=\frac{q_{2}}{R_{2}} \\
\frac{\sigma_{1}}{\sigma_{2}}= \\
\frac{q_{1}}{4 \pi \varepsilon_{o} R_{1}{ }^{2}} \times \frac{4 \pi \varepsilon_{o} R_{2}{ }^{2}}{q_{2}} \\
=\frac{q_{1}}{q_{2}} \times \frac{R_{2}{ }^{2}}{R_{1}{ }^{2}} \\
=\frac{R_{1}}{R_{2}} \times \frac{R_{2}{ }^{2}}{R_{1}{ }^{2}}=\frac{R_{2}}{R_{1}}
\end{gathered}
\] \\
(b) Current
\end{tabular} \& \(1 / 2\)
\(1 / 2\)

$1 / 2$
$1 / 2$
1 \& 3 <br>

\hline \[
$$
\begin{aligned}
& \hline \text { Set1,Q13 } \\
& \text { Set2,Q22 } \\
& \text { Set3,Q19 }
\end{aligned}
$$

\] \& | Readings of ideal ammeter and ideal voltmeter in fig (a) and (b) $11 / 2+11 / 2$ |
| :--- |
| In circuit (a) |
| Total emf=15 V |
| Total Resistance $=2 \Omega$ |
| Current $i=(15 / 2) \mathrm{A}=7.5 \mathrm{~A}$ |
| Potential Difference between the terminals of 6 V battery $\begin{aligned} & V=E-i R \\ & =[6-(7.5 \times 1)] \mathrm{V} \\ & =-1.5 \mathrm{~V} \end{aligned}$ |
| In circuit (b) $\begin{aligned} \text { Effective emf } & =(9-6) \mathrm{V} \\ & =3 \mathrm{~V} \end{aligned}$ |
| Current $\mathrm{i}=(3 / 2) \mathrm{A}=1.5 \mathrm{~A}$ |
| Potential Difference across 6 V cell $\begin{aligned} & V=E+i R \\ & =6+1.5 \times 1 \\ & =7.5 \mathrm{~V} \end{aligned}$ |
| OR |
| Finding current through each resistor |
| Total emf in the circuit $=8 \mathrm{~V}-4 \mathrm{~V}=4 \mathrm{~V}$ |
| Total resistance of the circuit $=8 \Omega$ |
| Hence current flowing in the circuit $\mathrm{i}=\frac{V}{R}=\frac{4}{8} \mathrm{~A}=0.5 \mathrm{~A}$ |
| Current flowing through the resistors: |
| Current throgh $0.5 \Omega, 1.0 \Omega$ and $4.5 \Omega$ is 0.5 A |
| Current through $3.0 \Omega$ is $\frac{1}{3} \mathrm{~A}$ |
| Current through $6.0 \Omega$ is $\frac{1}{6} \mathrm{~A}$ | \& $1 / 2$

$1 / 2$
1
1 \& 3 <br>
\hline
\end{tabular}



\begin{tabular}{|c|c|c|c|}
\hline \& \begin{tabular}{l}
For the solenoid : \\
Inductance, \(L=\mu_{0} n^{2} A l\); also \(\mathrm{B}=\mu_{0} n I\)
\[
\begin{aligned}
\& \therefore \mathrm{W}=U_{B}=\frac{1}{2} L I^{2} \\
\& \begin{aligned}
\& \frac{1}{2}\left(\mu_{o} n^{2} A l\right)\left(\frac{B}{\mu_{o} n}\right)^{2} \\
\& \quad=\frac{B^{2} A l}{2 \mu_{o}} \\
\& \Rightarrow \text { Magnetic energy per unt volume }=\frac{B^{2}}{2 \mu_{o}}
\end{aligned}
\end{aligned}
\] \\
Also, Electrostatic energy stored per unit volume \(=\frac{1}{2} \varepsilon_{o} E^{2}\)
\end{tabular} \& \(1 / 2\)

$1 / 2$
$1 / 2$
$1 / 2$
$1 / 2$ \& 3 <br>

\hline \[
$$
\begin{aligned}
& \hline \text { Set 1,Q16 } \\
& \text { Set2,Q13 } \\
& \text { Set3,Q22 }
\end{aligned}
$$

\] \& | (i) Calculation of rms value of current 2 <br> (ii) Calculation of total average power consumed. 1 |
| :--- |
| (i) $\begin{aligned} & X_{L}=\omega L=100 \times 80 \times 10^{-3}=8 \Omega \\ & X_{C}=\frac{1}{\omega C}=\frac{1}{100 \times 250 \times 10^{-6}} \Omega \\ & \quad=40 \Omega \end{aligned}$ |
| Total Impedence $(\mathrm{Z})=X_{C}-X_{L}$ $=32 \Omega$ $I_{r m s}=\frac{240}{32} \mathrm{~A}=7.5 \mathrm{~A}$ |
| (ii) Average power consumed $=0$ |
| (As there is no ohmic resistance in the current.) | \& $1 / 2$

$1 / 2$

$1 / 2$
$1 / 2$
$1 / 2$
1 \& 3 <br>

\hline \[
$$
\begin{aligned}
& \hline \text { Set1,Q17 } \\
& \text { Set2,Q14 } \\
& \text { Set3,Q11 }
\end{aligned}
$$

\] \& | Answers of part (i) and (ii) |
| :--- |
| $1^{1 / 2}+1^{1 / 2}$ |
| (i) It absorbs ultraviolet radiations from sun and prevents them from reaching on the earth's surface causing damage to life. |
| Identification : ultraviolet radiations |
| one correct application (=sanitization, forensics) |
| (ii) Water molecules present in most materials readily absorbs infra red waves. Hence, their thermal motion increases. Therefore, they heat their surroundings. |
| They are produced by hot bodies and molecules. Incoming visible light is absorbed by earth's surface and radiated as infra red radiations. These radiation are trapped by green house gases. | \& $1 / 2$

$1 / 2$
$1 / 2$
$1 / 2$
$1 / 2$
$1 / 2$
$1 / 2$ \& 3 <br>
\hline
\end{tabular}

\begin{tabular}{|c|c|c|c|}
\hline \begin{tabular}{l}
Set 1,Q18 \\
Set2,Q15 \\
Set3,Q12
\end{tabular} \& \begin{tabular}{l}
\begin{tabular}{ll}
\hline Definition of critical angle \& \(1 / 2\) \\
Drawing of Ray diagram \& 1 \\
Calculation of area of water surface. \& \(11 / 2\) \\
\hline
\end{tabular} \\
For an incident ray, travelling from an optically denser medium to optically rarer medium, the angle of incidence, for which the angle of refraction is \(90^{\circ}\), is called the critical angle. \\
Alternatively: \(\mu=\frac{1}{\sin i_{c}}\)
\[
i_{c}=\sin ^{-1}\left(\frac{1}{\mu}\right)
\]
\[
\begin{aligned}
\& \mu=\frac{1}{\sin i_{c}} \\
\& \sin i_{c}=\frac{3}{4} \\
\& \cos i_{c}=\frac{\sqrt{7}}{4} \\
\& \tan i_{c}=\frac{3}{\sqrt{7}}
\end{aligned}
\] \\
From figure,
\[
\tan i_{c}=\frac{x}{7} \Rightarrow \frac{3}{\sqrt{7}} \Rightarrow \frac{x}{7} \Rightarrow \mathrm{x}=3 \sqrt{7} \mathrm{~cm}
\] \\
Area \(=\pi x^{2}=63 \pi \mathrm{~cm}^{2}\)
\end{tabular} \& 1/2 \& 3 \\
\hline \[
\begin{aligned}
\& \text { Set1,Q19 } \\
\& \text { Set2,Q16 } \\
\& \text { Set3,Q13 }
\end{aligned}
\] \& \begin{tabular}{l}
Selection of lens for objective and eyepiece of \\
(i) Telescope \\
(ii) Microscope \\
(i) Telescope \\
\(L_{2}\) : objective \\
\(L_{3}\) : eyepiece \\
Reason \\
: Light gathering power and magnifying power will be larger. \\
(ii) Microscope \\
\(L_{3}\) : objective \\
\(L_{1}\) : eyepiece \\
Reason : Angular magnification is more for short focal length of objective and eyepiece.
\end{tabular} \& \(1 / 2\)
\(1 / 2\)
\(1 / 2\)

$1 / 2$
$1 / 2$
$1 / 2$ \& 3 <br>
\hline
\end{tabular}

| Set 1,Q20 <br> Set2,Q17 <br> Set3,Q14 | Explanation by drawing a suitable diagram 1 <br> Two basic features distinguishing interference pattern from <br> diffraction pattern $1+1$ diffraction pattern <br> The diagram, given here, shows several fringes, due to double slit interference, 'contained' in a broad diffraction peak. When the seperation between the slits is large compared to their width, the diffraction pattern becomes very flat and we observe the two slit interference pattern. <br> [Note: The students may be awarded 1 mark even if they just draw the diagram.] <br> Two basic features: <br> (i) The interference pattern has a number of equally spaced bright and dark bands while differaction pattern has a central bright maximum which is twice as wide as the other maxima. <br> (ii) Interference pattern is the superimposition of two waves slits originating from two narrow sects. The differaction pattern is a superposition of a continuous family of waves originating from each point on a single slit. <br> (iii) For a single slit of width ' $a$ ' the first null of differaction pattern occurs at an angle of $\frac{\lambda}{a}$. At the same angle of $\lambda / a$, we get a maxima for two narrow slits seperated by a distance a. <br> [ Any two of the above distinguishing features.] | 1/2 | 3 |
| :---: | :---: | :---: | :---: |
| $\begin{aligned} & \hline \text { Set1,Q21 } \\ & \text { Set2,Q18 } \\ & \text { Set3,Q15 } \end{aligned}$ | Distinction between n - type and p -type semi conductors on the basis of Energy band diagrams <br> Comparison of conductivities <br> (a) $T>0 \mathrm{~K}$ electron-hole <br> pair +9 electrons from donor atoms <br> (i) In n - type semi conductors an extra energy level (called donor energy level) is produced just below the bottom of the conduction band, while in the p-type ssemiconductor, this extra energy band (called acceptor energy level) is just above the top of the balance band. <br> (ii) In n - type semiconductors, most of the electrons come from the donor impurity while in p-type semi conductor, the density of holes in | 1/2 |  |


|  | the valence band is predominantlly due to the impurity in the extrinsic semiconductors. <br> [Any one of the above, or any one, other, correct distinguishing feature.] At absolute zero temperature conductivities of both type of semi-conductors will be zero. <br> For equal doping, an n-type semi conductor will have more conductivity than a p-type semiconductor, at room temperature. | $\begin{aligned} & 1 / 2 \\ & 1 / 2 \end{aligned}$ | 3 |
| :---: | :---: | :---: | :---: |
| Set1,Q22 Set2,Q19 Set3,Q16 | (a) Identification of $X$ and $Y$ <br> Their functions <br> (b) $1 / 2+1 / 2$ <br> Distinction between point to point and broadcast <br> $1 / 2+1 / 2$ <br> mode. 1 <br> (a) : Transmitter <br> Y: Channel  <br> Their functions:  <br> Transmitter : To convert the message signal into suitables form for  <br> transmission through channel.  <br> Channel : It sends the signal to the reciever.  <br> (b)In point to point mode, communication takes place between a <br> single transmitter and receiver. In broadcast mode, large number <br> of receivers are connected to a single transmitter.  | $\begin{aligned} & 1 / 2 \\ & 1 / 2 \\ & 1 / 2 \\ & 1 / 2 \\ & 1 \end{aligned}$ | 3 |
| Section D |  |  |  |
| $\begin{aligned} & \hline \text { Set1,Q23 } \\ & \text { Set2,Q23 } \\ & \text { Set3,Q23 } \end{aligned}$ | (i) Qualities / values of Rohit. 1 <br> (ii) Advantage of CFLs/ LEDs over traditional  <br> (iii) incandescent lamps. Role of earthing in reduction of electricity bills 11 <br> (i) Co-operative attitude and scientific temperament. (or any other two correct values.) <br> (ii) a) Low operational voltage and less power. <br> b) fast action and no warm up time required. <br> (Any one) <br> (iii) In the absence of proper earthing, the consumer can get (extra) charges for the electrical energy NOT consumed by the devices in her/his premises. | $1+1$ <br> 1 <br> 1 | 4 |
| Section E |  |  |  |
| $\begin{aligned} & \hline \text { Set1,Q24 } \\ & \text { Set2,Q26 } \end{aligned}$ Set3,Q26 | (a) Derivation of the expression <br> 2 <br> (b) Magnetic field lines due to the coil <br> 1 <br> (c) Magnetic field at the center of the loop <br> (a) | 1/2 |  |
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According to Biot- Savart law,

$$
\begin{gathered}
d \vec{B}=\frac{\mu_{o}}{4 \pi} \frac{I(\overrightarrow{d l} \times \vec{r})}{r^{3}} \\
d B=\frac{\mu_{o}}{4 \pi} \frac{I d l}{\left(x^{2}+R^{2}\right)}\left[\begin{array}{l}
\because|\overrightarrow{d l} \times \vec{r}|=r d l ; \\
r=\left(x^{2}+R^{2}\right)^{\frac{1}{2}}
\end{array}\right]
\end{gathered}
$$

From figure

$$
\cos \theta=\frac{R}{\left(x^{2}+R^{2}\right)^{\frac{1}{2}}}
$$

$\therefore$ Net contribution along x-direction
$B=\sum_{2 \pi R} d B \cos \theta=\int d B \cos \theta$
$=\int_{0}^{2 \pi R} \frac{\mu_{o} I d l}{4 \pi} \frac{R}{\left(x^{2}+R^{2}\right)^{\frac{3}{2}}}$
$\vec{B}=\frac{\mu_{o} I R^{2}}{2\left(R^{2}+x^{2}\right)^{\frac{3}{2}}} \hat{\imath}$

(b) Let current I be divided at point M into two parts $\mathrm{I}_{1}$ and $\mathrm{I}_{2}$; in bigger and smaller parts of the loop respectively.
Magnetic field of current $\mathrm{I}_{1}$ at point O
$\overrightarrow{B_{1}}=\frac{\mu_{o} I_{1}}{2 R} \times \frac{1}{4} \otimes$
Magnetic field of current $\mathrm{I}_{2}$ at point O
$\overrightarrow{B_{2}}=\frac{\mu_{o} I_{2}}{2 R} \times \frac{3}{4} \odot$
Net magnetic field $\vec{B}=\overrightarrow{B_{1}}+\overrightarrow{B_{2}}$
$|\vec{B}|=\frac{\mu_{o} I_{1}}{8 R}-\frac{\mu_{o} I_{2}}{8 R}---------------\left(1_{2}\right)$
But $\mathrm{I}_{1}=3 \mathrm{I}_{2}$ (As resistance of bigger part is three times that of the smaller part of the loop.)
Substituting $\mathrm{I}_{1}=3 \mathrm{I}_{2}$ in equation (1)
$\Rightarrow|\vec{B}|=0$


## OR

(a) Derivation of expression of magnetic field inside solenoid 3
(b) Finding the magnitude and direction of Magnetic field

Any surface carrying current can be divided into small line elements, each of length ' $d l$ '. Considering the tangential components of the magnetic field and finding $\vec{B} \cdot \overrightarrow{d l}$, sum of all elements tends to the integral, which can be expressed in the following form. : $\oint \vec{B} \cdot \overrightarrow{d l}=\mu_{o} i$, This form is known as Ampers's circuital law.

(b)

I


|  | As per the given figure, magnetic field must be vertically inwards, to make tension zero, (If a student shows current in opposite direction the magnetic field should be set up vertically upwards. $I l B=m g$ <br> For tension to be zero $\begin{aligned} B=\frac{m g}{I l} & =\frac{60 \times 10^{-3} \times 9.8}{5.0 \times 0.45} \mathrm{~T} \\ & =0.26 \mathrm{~T} \end{aligned}$ | $1 / 2$ $1 / 2$ $1 / 2$ $1 / 2$ | 5 |
| :---: | :---: | :---: | :---: |
| $\begin{aligned} & \hline \text { Set1,Q25 } \\ & \text { Set2,Q24 } \\ & \text { Set3,Q25 } \end{aligned}$ | (a) Schematic arrangement of Greiger-Marsden Experiment Reason <br> (b) Estimation of the distance of closest approach <br> (a) <br> For most of the $\alpha$-particles, impact parameter is large, hence they suffer very small repulsion due to nucleus and go right through the foil. <br> It gives an estimate of the size of nucleus. <br> (b) K.E of the $\alpha$-particle $=$ potential energy possesed by beam at distance of closest approach. $\frac{1}{2} m v^{2}=\frac{1}{4 \pi \epsilon_{o}} \cdot \frac{(2 e)(Z e)}{r_{0}}$ | 1 1 |  |


|  |  |  |  |
| :---: | :---: | :---: | :---: |




